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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Radial Lead Type

OS-CON



Series : **SEP**

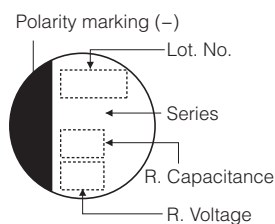
Features

- Standard
- 105 °C 3000 h
- RoHS compliance, Halogen free

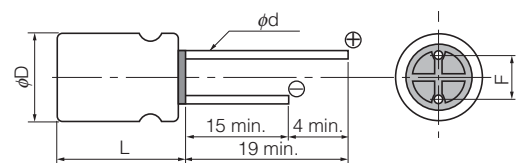
Specifications

Size code	C6	E7	F8	E12	F13
Category temperature range	-55 °C to +105 °C				
Rated voltage range	4 V.DC to 20 V.DC			2.5 V.DC to 20 V.DC	
Rated capacitance range	22 μF to 150 μF	33 μF to 330 μF	56 μF to 680 μF	100 μF to 680 μF	150 μF to 1500 μF
Capacitance tolerance	±20 % (120 Hz / + 20 °C)				
Leakage current	Please see the attached characteristics list				
Dissipation factor (tan δ)	Please see the attached characteristics list				
Endurance	+105 °C, 3000 h, rated voltage applied (2.5 V.DC 2000 h applied)				
	Capacitance change	Within ±20 % of the initial value			
	tan δ	≤ 150 % of the initial limit			
	DC leakage current	Within the initial limit			
Damp heat (Steady State)	+60 °C, 90 % to 95 %, 1000 h, No-applied voltage				
	Capacitance change	Within ±20 % of the initial value			
	tan δ	≤ 150 % of the initial limit			
	DC leakage current	Within the initial limit (after voltage processing)			

Marking



Dimensions (not to scale)



Unit : mm

Size code	φD±0.5	L max.	F±0.5	φd±0.05
C6	6.3	6.0	2.5	0.45
E7	8.0	7.0	3.5	0.45
F8	10.0	8.0	5.0	0.50
E12	8.0	12.0	3.5	0.60
F13	10.0	13.0	3.5	0.60

* Externals of figure are the reference.

Characteristics list

Series	Rated voltage (V.DC)	Rated capacitance (μF)	Case size (mm)		Size code	Specifications				Part number
			φD	L		Ripple* ¹ current (mA r.m.s.)	ESR* ² (mΩ max.)	tan δ* ³	LC* ⁴ (μA)	
SEP	2.5	680	8.0	12.0	E12	4520	13	0.15	340	2R5SEP680M
		1500	10.0	13.0	F13	5440	12	0.18	750	2R5SEP1500M
	4.0	100	6.3	6.0	C6	1810	40	0.12	200	4SEP100M
		150	6.3	6.0		1810	40	0.12	300	4SEP150M
		220	8.0	7.0	E7	2560	35	0.12	440	4SEP220M
		330	8.0	7.0		2560	35	0.12	660	4SEP330M
		470	10.0	8.0	F8	3700	25	0.12	376	4SEP470M
		560	8.0	12.0	E12	4520	13	0.15	448	4SEP560M
		680	10.0	8.0	F8	3700	25	0.12	544	4SEP680M
		1200	10.0	13.0	F13	5440	12	0.18	960	4SEP1200M
	6.3	82	6.3	6.0	C6	1700	45	0.12	258	6SEP82M
		150	8.0	7.0	E7	2560	35	0.12	472	6SEP150M
		330	10.0	8.0	F8	3700	25	0.12	416	6SEP330M
		470	8.0	12.0	E12	4210	15	0.15	592	6SEP470M
		820	10.0	13.0	F13	5440	12	0.15	775	6SEP820M
	10	56	6.3	6.0	C6	1700	45	0.12	280	10SEP56M
		120	8.0	7.0	E7	2560	35	0.12	600	10SEP120M
		270	10.0	8.0	F8	3700	25	0.12	540	10SEP270M
		330	8.0	12.0	E12	3950	17	0.15	660	10SEP330M
		560	10.0	13.0	F13	5230	13	0.15	840	10SEP560M
	16	39	6.3	6.0	C6	1620	50	0.10	312	16SEP39M
		82	8.0	7.0	E7	2120	40	0.12	656	16SEP82M
		150	10.0	8.0	F8	3020	30	0.12	480	16SEP150M
		180	8.0	12.0	E12	3640	20	0.15	576	16SEP180M
		330	10.0	13.0	F13	4720	16	0.15	792	16SEP330M
	20	22	6.3	6.0	C6	1450	60	0.10	220	20SEP22M
		33	8.0	7.0	E7	1890	45	0.12	330	20SEP33M
		47	8.0	7.0		1890	45	0.12	470	20SEP47M
		56	10.0	8.0		F8	2400	40	0.12	224
		68	10.0	8.0	2400		40	0.12	272	20SEP68M
100		10.0	8.0	2570	35		0.12	400	20SEP100MX	
		8.0	12.0	E12	3320		24	0.15	400	20SEP100M
150		10.0	13.0	F13	4320	20	0.15	600	20SEP150M	

*1 Ripple current (100 kHz/ +105 °C), *2 ESR (100 kHz to 300 kHz/+20 °C) *3 tan δ (120 Hz/+20 °C) *4 After 2 minutes

◆ Please refer to each page in this catalog for "Flow conditions" and "Taping specifications".

Frequency correction factor for ripple current

Frequency	120 Hz ≤ f < 1 kHz	1 kHz ≤ f < 10 kHz	10 kHz ≤ f < 100 kHz	100 kHz ≤ f < 500 kHz
Coefficient	0.05	0.3	0.7	1